www.omseni.com

OM SENI

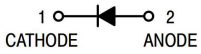
MMDL301T1G
Silicon Hot-Carrier Diodes
Schottky Barrier Diode

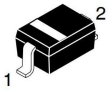
These devices are designed primarily for high−efficiency UHF and VHF detector applications. They are readily adaptable to many other fast switching RF and digital applications. They are supplied in an inexpensive plastic package for low−cost, high−volume consumer and industrial/commercial requirements. They are available in a Surface Mount package.

Features

- Extremely Low Minority Carrier Lifetime − 15 ps (Typ)
- Very Low Capacitance − 1.5 pF (Max) @ V_R = 15 V
- Low Reverse Leakage − I_R = 13 nAdc (Typ)
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

30 VOLTS SILICON HOT−CARRIER DETECTOR AND SWITCHING DIODES





PLASTIC
SOD−323
CASE 477
STYLE 1

MAXIMUM RATINGS (T_J = 125°C unless otherwise noted)

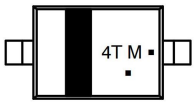
Rating	Symbol	Value	Unit
Reverse Voltage	V_R	30	V

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR−5 Board, (Note 1) @T_A = 25°C Derate above 25°C	P_D	200 1.57	mW mW/°C
Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	635	°C/W
Junction and Storage Temperature Range	T_J, T_{stg}	−55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
1. FR−5 Minimum Pad

MARKING DIAGRAM



4T = Device Code
M = Date Code*
▪ = Pb−Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage (I_R = 10 μA)	$V_{(BR)R}$	30	−	−	V
Total Capacitance (V_R = 15 V, f = 1.0 MHz) Figure 1	C_T	−	0.9	1.5	pF
Reverse Leakage (V_R = 25 V) Figure 3	I_R	−	13	200	nAdc
Forward Voltage (I_F = 1.0 mAdc) Figure 4	V_F	−	0.38	0.45	Vdc
Forward Voltage (I_F = 10 mAdc) Figure 4	V_F	−	0.52	0.6	Vdc

www.omseni.com

OM SENI

TYPICAL ELECTRICAL CHARACTERISTICS

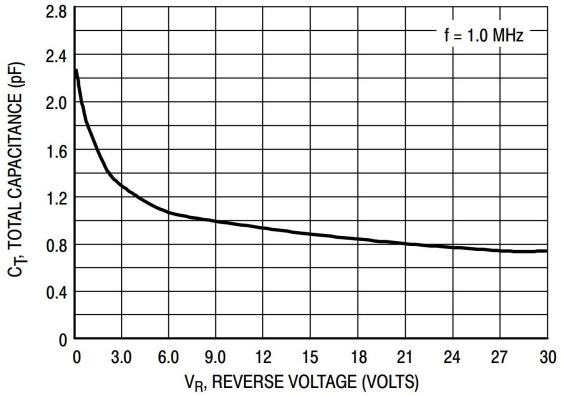


Figure 1. Total Capacitance

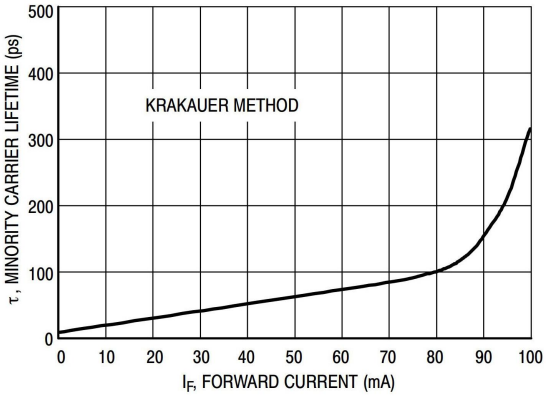


Figure 2. Minority Carrier Lifetime

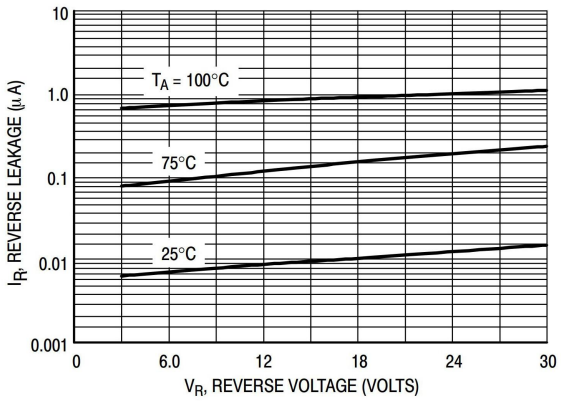


Figure 3. Reverse Leakage

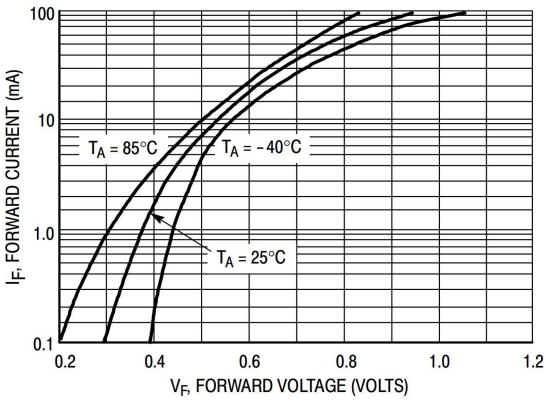


Figure 4. Forward Voltage

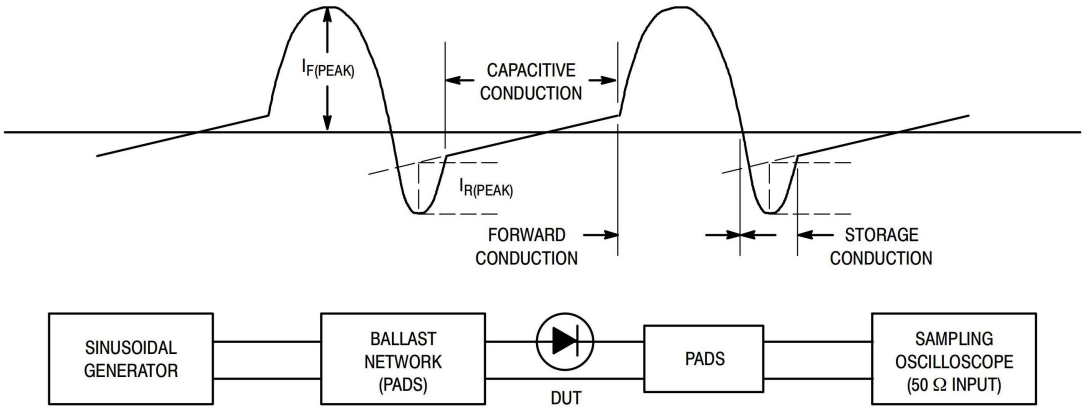


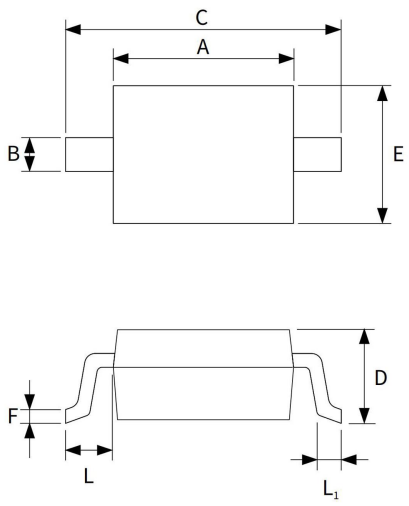
Figure 5. Krakauer Method of Measuring Lifetime

OM SENI

Ordering Information

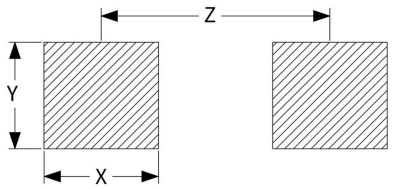
PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SOD-323	R1	0.0048	3000	30000	240000	7''

Package Outline Dimensions (SOD-323)



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	1.60	1.80	0.063	0.071
B	0.25	0.40	0.010	0.016
C	2.30	2.80	0.091	0.110
D	0.80	1.10	0.031	0.043
D_1	0.80	0.90	0.031	0.035
E	1.20	1.40	0.047	0.055
F	0.08	0.18	0.003	0.007
L	0.475REF		0.019REF	
L_1	0.25	0.40	0.010	0.016
H	-	0.14	-	0.006

Suggested Pad Layout



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
X	0.65	0.75	0.026	0.030
Y	0.65	0.75	0.026	0.030
Z	2.10	2.20	0.084	0.088